Docket No. 1384.1038 (JDH)

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Bernd SCHöTTKER, et al.

Serial No.: To be assigned

Examiner: Unassigned

Group Art Unit: Unassigned

Filed: July 26, 2000

METHOD OF GROWING NITROGENOUS SEMICONDUCTOR CRYSTAL

**MATERIALS** 

## PRELIMINARY AMENDMENT

**Assistant Commissioner for Patents** 

Washington, D.C. 20231

Sir:

Before examination of the above-identified application, please amend the application as

• follows:

## **IN THE CLAIMS:**

Please AMEND the claims as follows:

Claim 3,

line 1, delete "or 2".

Claim 4,

line 1, change "any of the Claims 1 to 3" to --Claim 1--.